Low Power Peak EMI Reducing Solution

ON Semiconductor[®]



Features

- Generates an EMI optimized clock signal at the output.
- Integrated loop filter components.
- Operates with a 3.3V / 2.5V supply.
- Operating current less than 6mA.
- Low power CMOS design.
- Input frequency range: 13MHz to 30MHz for 2.5V 13MHz to 30MHz for 3.3V
- Generates a 1X low EMI spread spectrum clock of the input frequency.
- Frequency deviation: -1.25% @ 22MHz.
- Available in 6-pin TSOT-23, 8-pin SOIC and 8-pin TSSOP packages.

Product Description

The ASM3P2872A is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The ASM3P2872A reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of all clock dependent signals. The ASM3P2872A allows significant system cost savings by reducing the number of circuit board layers, ferrite beads and shielding that are traditionally required to pass EMI regulations.

The ASM3P2872A uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all digital method.

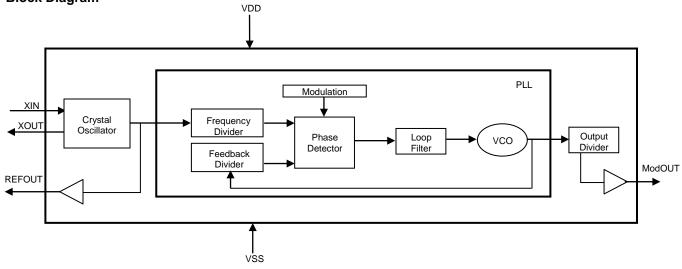
The ASM3P2872A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation.'

Applications

The ASM3P2872A is targeted towards all portable devices with very low power requirements like MP3 players, Notebooks and digital still cameras.

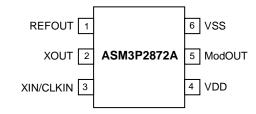
Key Specifications

Description	Specification
Supply voltages	VDD = 3.3V /2.5V
Cycle-to-Cycle Jitter	200pS (Max)
Output Duty Cycle	45/55% (worst case)
Modulation Rate Equation	F _{IN} /640
Frequency Deviation	-1.25% @ 22MHz



Block Diagram

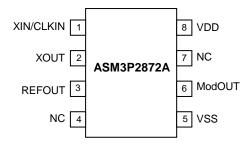
Pin Configuration (6-pin TSOT-23 Package)



Pin Description

Pin#	Pin Name	Туре	Description			
1	REFOUT	0	Buffered output of the input frequency.			
2	XOUT	OUT O Crystal connection. If using an external reference, this pin must be left unconnected.				
3	3 XIN / CLKIN I Crystal connection or external reference frequency input. This pin has dual function can be connected either to an external crystal or an external reference clock.		Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock.			
4	VDD	Р	Power supply for the entire chip.			
5	ModOUT	0	Spread spectrum clock output.			
6	VSS	Р	Ground connection.			

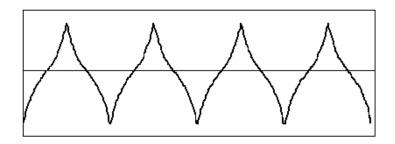
Pin Configuration (8-pin SOIC and TSSOP Packages)



Pin Description

Pin#	Pin Name	Туре	Description
1	XIN / CLKIN	Ι	Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock.
2	XOUT	0	Crystal connection. If using an external reference, this pin must be left unconnected.
3	REFOUT	0	Buffered output of the input frequency.
4	NC	-	No connect.
5	VSS	Р	Ground connection.
6	ModOUT	0	Spread spectrum clock output.
7	NC	-	No connect.
8	VDD	Ρ	Power supply for the entire chip.

Modulation Profile



Specifications

Description		Specification
Fraguenov Bongo	For 2.5V Supply	13MHz < CLKIN < 30MHz
Frequency Range	For 3.3V Supply	13MHz < CLKIN < 30MHz
Modulation Equation		F _{IN} /640
Frequency Deviation		-1.25% @ 22MHz

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit			
VDD, V _{IN}	Voltage on any pin with respect to Ground	-0.5 to +4.6	V			
T _{STG}	Storage temperature	-65 to +125	°C			
T _A	Operating temperature	-40 to +85	°C			
Ts	Max. Soldering Temperature (10 sec)	260	°C			
TJ	Junction Temperature	150	°C			
T _{DV}	Static Discharge Voltage (As per JEDEC STD22- A114-B)	2	KV			
	Note: These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability.					

DC Electrical Characteristics for 2.5V Supply (Test condition: All parameters are measured at room temperature (+25°C) unless otherwise stated.)

Symbol	Parameter	Min	Тур	Мах	Unit
VIL	Input low voltage	VSS-0.3	-	0.8	V
V _{IH}	Input high voltage	2.0	-	VDD+0.3	V
IIL	Input low current	-	-	-35	μA
I _{IH}	Input high current	-	-	35	μA
I _{XOL}	XOUT output low current (@ 0.5V, VDD = 2.5V)	-	3	-	mA
I _{хон}	XOUT output high current (@ 1.8V, VDD = 2.5V)	-	3	-	mA
V _{OL}	Output low voltage (VDD = 2.5 V, I _{OL} = 8mA)	-	-	0.6	V
V _{OH}	Output high voltage (VDD = 2.5 V , $I_{OH} = 8\text{mA}$)	1.8	-	-	V
I _{DD}	Static supply current ¹	-	1.1	-	mA
Icc	Dynamic supply current (2.5V, 30MHz and with no load)	-	4.0	-	mA
VDD	Operating voltage	2.375	2.5	2.625	V
t _{ON}	Power-up time (first locked cycle after power-up)	-	-	5	mS
Z _{OUT}	Output impedance	-	50	-	Ω
Note: 1. XIN	CLKIN pin is pulled low.	•		•	

AC Electrical Characteristics for 2.5V Supply

Symbol	Pa	Min	Тур	Max	Unit	
CLKIN	Input frequency		13	-	30	MHz
ModOUT	Output frequency		13	-	30	MHz
£	Fraguency Deviation	Input Frequency = 13MHz	-	-1.85	-	%
f _d	Frequency Deviation	Input Frequency = 30MHz	-	-0.9	-	
t _{LH} 1	Output rise time (measu	red from 0.7V to 1.7V)	0.7	1.5	1.7	nS
t _{HL} 1	Output fall time (measur	red from 1.7V to 0.7V)	0.5	0.9	1.1	nS
tuc	Jitter (cycle-to-cycle)		-	-	200	pS
t _D	Output duty cycle		45	50	55	%
Note: 1. t_{LH} and t_{HL}	are measured into a capacitive le	oad of 15pF.	•			

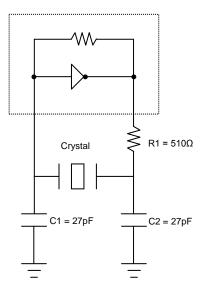
DC Electrical Characteristics for 3.3V Supply (Test condition: All parameters are measured at room temperature (+ 25°C) unless otherwise stated.)

Symbol	Parameter	Min	Тур	Max	Unit
VIL	Input low voltage	VSS-0.3	-	0.8	V
VIH	Input high voltage	2.0	-	VDD+0.3	V
I _{IL}	Input low current	-	-	-35	μA
I _{IH}	Input high current	-	-	35	μA
I _{XOL}	XOUT output low current (@ 0.4V, VDD = 3.3V)	-	3	-	mA
I _{XOH}	XOUT output high current (@ 2.5V, VDD = 3.3V)	-	3	-	mA
V _{OL}	Output low voltage (VDD = 3.3 V, I _{OL} = 8mA)	-	-	0.4	V
V _{OH}	Output high voltage (VDD = 3.3 V , $I_{OH} = 8\text{mA}$)	2.5	-	-	V
I _{DD}	Static supply current ¹	-	1.2	-	mA
I _{CC}	Dynamic supply current (3.3V, 30MHz and with no load)	-	5.5	-	mA
VDD	Operating voltage	2.7	3.3	3.6	V
t _{ON}	Power-up time (first locked cycle after power-up)	-	-	5	mS
Z _{OUT}	Output impedance	-	45	-	Ω
Note: 1. XIN	CLKIN pin is pulled low.		•	•	•

AC Electrical Characteristics for 3.3V Supply

Symbol	Pa	Parameter			Max	Unit
CLKIN	Input frequency		13	-	30	MHz
ModOUT	Output frequency		13	-	30	MHz
4	Fraguency Deviation	Input Frequency = 13MHz	-	-1.85	-	%
f _d	Frequency Deviation Input Frequency = 30MHz	-	-0.9	-	70	
t _{LH} ¹	Output rise time (measu	Output rise time (measured from 0.8 to 2.0V)		1.4	1.7	nS
t _{HL} ¹	Output fall time (measur	ed at 2.0V to 0.8V)	0.4	0.9	1.1	nS
t _{JC}	Jitter (cycle-to-cycle)	Jitter (cycle-to-cycle)		-	200	pS
t _D	Output duty cycle		45	50	55	%
Note: 1. t_{LH} and t_{HL} are	measured into a capacitive load of	15pF.				

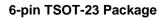
Typical Crystal Oscillator Circuit

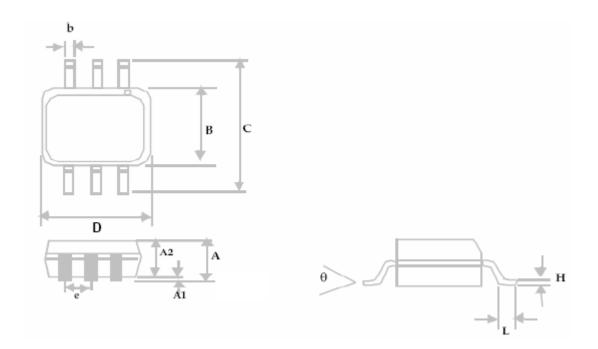


Typical Crystal Specifications

Fundamental AT cut parallel resonant crystal				
Nominal frequency	14.31818MHz			
Frequency tolerance	±50ppm or better at 25°C			
Operating temperature range	-25°C to +85°C			
Storage temperature	-40°C to +85°C			
Load capacitance	18pF			
Shunt capacitance	7pF maximum			
ESR	25Ω			

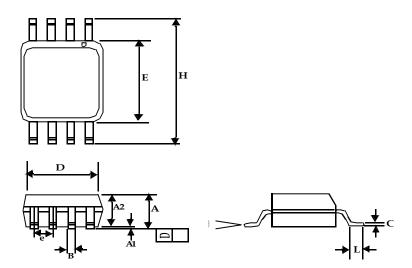
Package Information





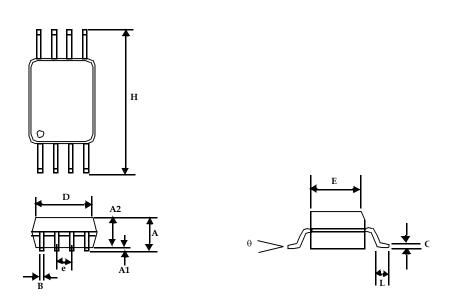
		Dimensions				
Symbol	Inches		Millim	neters		
	Min	Мах	Min	Мах		
А		0.04		1.00		
A1	0.00	0.004	0.00	0.10		
A2	0.033	0.036	0.84	0.90		
b	0.012	0.02	0.30	0.50		
Н	0.005	BSC	0.127	BSC		
D	0.114	BSC	2.90	BSC		
В	0.06	BSC	1.60	BSC		
е	0.0374 BSC		0.950	BSC		
С	0.11	BSC	2.80 BSC			
L	0.0118	0.02	0.30	0.50		
θ	0°	4°	0°	4°		





	Dimensions				
Symbol	Inches		Millim	neters	
	Min	Max	Min	Max	
A1	0.004	0.010	0.10	0.25	
А	0.053	0.069	1.35	1.75	
A2	0.049	0.059	1.25	1.50	
В	0.012	0.020	0.31	0.51	
С	0.007	0.010	0.18	0.25	
D	0.193	BSC	4.90	BSC	
Е	0.154	BSC	3.91	BSC	
е	0.050 BSC		1.27	BSC	
Н	0.236	BSC	6.00 BSC		
L	0.016	0.050	0.41	1.27	
θ	0°	8°	0°	8°	

8-Pin TSSOP

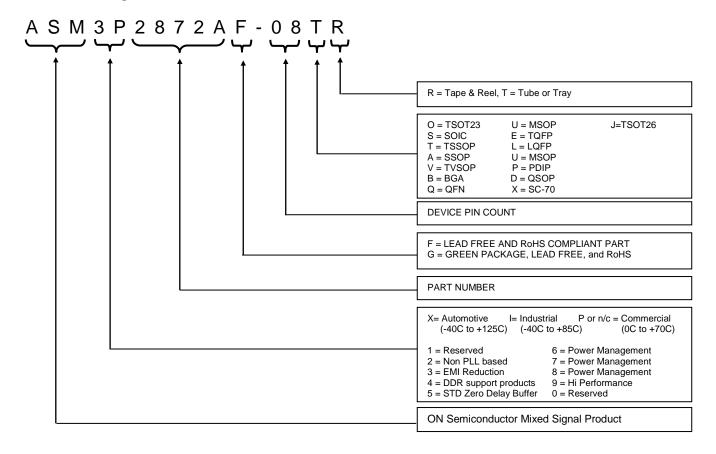


	Dimensions				
Symbol	Inches		Millimeters		
	Min	Мах	Min	Max	
А		0.043		1.10	
A1	0.002	0.006	0.05	0.15	
A2	0.033	0.037	0.85	0.95	
В	0.008	0.012	0.19	0.30	
С	0.004	0.008	0.09	0.20	
D	0.114	0.122	2.90	3.10	
E	0.169	0.177	4.30	4.50	
е	0.026 BSC		0.65 BSC		
Н	0.252 BSC		6.40 BSC		
L	0.020	0.028	0.50	0.70	
θ	0°	8°	0°	8°	

Ordering Information

Part Number	Marking	Package Type	Temperature
ASM3P2872AF-06OR	B4LL	6-Pin TSOT-23, TAPE & REEL, Pb Free	Commercial
ASM3P2872AF-08TT	3P2872AF	8-Pin TSSOP, TUBE, Pb Free	Commercial
ASM3P2872AF-08TR	3P2872AF	8-Pin TSSOP, TAPE & REEL, Pb Free	Commercial
ASM3P2872AF-08ST	3P2872AF	8-Pin SOIC, TUBE, Pb Free	Commercial
ASM3P2872AF-08SR	3P2872AF	8-Pin SOIC, TAPE & REEL, Pb Free	Commercial
ASM3P2872AG-06OR	B3LL	6-Pin TSOT-23, TAPE & REEL, Green	Commercial
ASM3P2872AG-08TT	3P2872AG	8-Pin TSSOP, TUBE, Green	Commercial
ASM3P2872AG-08TR	3P2872AG	8-Pin TSSOP, TAPE & REEL, Green	Commercial
ASM3P2872AG-08ST	3P2872AG	8-Pin SOIC, TUBE, Green	Commercial
ASM3P2872AG-08SR	3P2872AG	8-Pin SOIC, TAPE & REEL, Green	Commercial
ASM3I2872AF-06OR	B5LL	6-Pin TSOT-23, TAPE & REEL, Pb Free	Industrial
ASM3I2872AF-08TT	3I2872AF	8-Pin TSSOP, TUBE, Pb Free	Industrial
ASM3I2872AF-08TR	3I2872AF	8-Pin TSSOP, TAPE & REEL, Pb Free	Industrial
ASM3I2872AF-08ST	3I2872AF	8-Pin SOIC, TUBE, Pb Free	Industrial
ASM3I2872AF-08SR	3I2872AF	8-Pin SOIC, TAPE & REEL, Pb Free	Industrial
ASM3I2872AG-06OR	B6LL	6-Pin TSOT-23, TAPE & REEL, Green	Industrial
ASM3I2872AG-08TT	3I2872AG	8-Pin TSSOP, TUBE, Green	Industrial
ASM3I2872AG-08TR	3I2872AG	8-Pin TSSOP, TAPE & REEL, Green	Industrial
ASM3I2872AG-08ST	3I2872AG	8-Pin SOIC, TUBE, Green	Industrial
ASM3I2872AG-08SR	3I2872AG	8-Pin SOIC, TAPE & REEL, Green	Industrial

Device Ordering Information



Licensed under US Patent #5,488,627 and #5,631,921.

Note: This product utilizes US Patent #6,646,463 Impedance Emulator Patent issued to PulseCore Semiconductor, dated 11-11-2003.

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